

Elektrische Eigenschaften

Electrical properties

Höchstzulässige Werte

Maximum rated values

Periodische Vorwärts- und Rückwärts-Sperrspannung	repetitive peak forward off-state and reverse voltages	$t_{vj} = -40^{\circ}\text{C} \dots t_{vj\text{ max}}$	$V_{\text{DRM}}, V_{\text{RRM}}$	1600, 1800 V
Vorwärts-Stoßspitzen-sperrspannung	non repetitive peak forward off-state voltage	$t_{vj} = -40^{\circ}\text{C} \dots t_{vj\text{ max}}$	$V_{\text{DSM}} = V_{\text{DRM}}$	2000* v
Rückwärts-Stoßspitzen-sperrspannung	non repetitive peak reverse voltage	$t_{vj} = +25^{\circ}\text{C} \dots t_{vj\text{ max}}$	$V_{\text{RSM}} = V_{\text{RRM}}$	+ 100 v
Durchlaßstrom-Grenzeffektivwert	RMS on-state current	$t_c = 85^{\circ}\text{C}$	I_{TRMSM}	2000 A
Dauergrenzstrom	average on-state current	$t_c = 62^{\circ}\text{C}$	I_{TAVM}	930 A
				1274 A
Stoßstrom-Grenzwert	surge current	$t_{vj} = 25^{\circ}\text{C}, t_p = 10\text{ ms}$	I_{TSM}	20,5 kA
		$t_{vj} = t_{vj\text{ max}}, t_p = 10\text{ ms}$		18 kA
Grenzlastintegral	I^2t -value	$t_{vj} = 25^{\circ}\text{C}, t_p = 10\text{ ms}$	I^2t	2100 kA ² s
		$t_{vj} = t_{vj\text{ max}}, t_p = 10\text{ ms}$		1 6 2 0 kA ² s
Kritische Stromsteilheit	critical rate of rise of on-state current	$V_D \leq 67\% V_{\text{DRM}}, f = 50\text{ Hz}$	$(di/dt)_{\text{cr}}$	250 A/ μs
Kritische Spannungssteilheit	critical rate of rise of off-state voltage	$i_{\text{GM}} = 1,2\text{ A}, di_G/dt = 1,2\text{ A}/\mu\text{s}$	$(dv/dt)_{\text{cr}}$	1) 50 V/ μs 2) 50 V/ μs
		$t_{vj} = t_{vj\text{ max}}, V_D = 67\% V_{\text{DRM}}$	C*: 500 V/ μs L: 500 V/ μs M*: 1000 V/ μs	500 V/ μs 50 V/ μs 500 V/ μs

Charakteristische Werte

Characteristic values

Durchlaßspannung	on-state voltage	$t_{vj} = t_{vj\text{ max}}, I_T = 3500\text{ A}$	V_T	max. 2,7 V
Schleusenspannung	threshold voltage	$t_{vj} = t_{vj\text{ max}}$	$V_{T(\text{TO})}$	1,35 v
Ersatzwiderstand	slope resistance	$t_{vj} = t_{vj\text{ max}}$	r_T	0,33 m Ω
Zündstrom	gate trigger current	$t_{vj} = 25^{\circ}\text{C}, V_D = 12\text{ V}$	I_{GT}	max. 250 mA
Zündspannung	gate trigger voltage	$t_{vj} = 25^{\circ}\text{C}, V_D = 12\text{ V}$	V_{GT}	max. 2,2 v
Nicht zündender Steuerstrom	gate non-trigger current	$t_{vj} = t_{vj\text{ max}}, V_D = 12\text{ V}$	I_{GD}	max. 10 mA
Nicht zündende Steuerspannung	gate non-trigger voltage	$t_{vj} = t_{vj\text{ max}}, V_D = 0,5 V_{\text{DRM}}$	V_{GD}	max. 0,25 v
Haltestrom	holding current	$t_{vj} = 25^{\circ}\text{C}, V_D = 12\text{ V}, R_A = 10\text{ }\Omega$	I_H	max. 300 mA
Einraststrom	latching current	$t_{vj} = 25^{\circ}\text{C}, V_D = 12\text{ V}, R_{\text{GK}} \geq 10\text{ }\Omega$	I_L	max. 1,5 A
		$i_{\text{GM}} = 1,2\text{ A}, di_G/dt = 1,2\text{ A}/\mu\text{s}, t_g = 20\text{ ps}$		
Vorwärts- u. Rückwärts-Sperrstrom	forward off-state and reverse Currents	$t_{vj} = t_{vj\text{ max}}, V_D = V_{\text{DRM}}, V_R = V_{\text{RRM}}$	i_D, i_R	max. 200 mA
Zündverzug	gate controlled delay time	$t_{vj} = 25^{\circ}\text{C}, i_{\text{GM}} = 1,2\text{ A}, di_G/dt = 1,2\text{ A}/\mu\text{s}$	t_{gd}	max. 1,4 μs
Freiwerdezeit	circuit commutated turn-off time	siehe Techn. Erl./see Techn. Inf.	t_q	K: max. 40 μs M: max. 50 μs N: max. 60 μs

Thermische Eigenschaften

thermal properties

Innerer Wärmewiderstand für beidseitige Kühlung	thermal resistance, junction to case for two-sided cooling	$\Theta = 180^{\circ}\text{ el, sin}$ DC	R_{thJC}	max. 0,021 $^{\circ}\text{C}/\text{W}$ max. 0,02 $^{\circ}\text{C}/\text{W}$
für anodenseitige Kühlung	for anode-sided cooling	$\Theta = 160^{\circ}\text{ el, sin}$ DC	$R_{\text{thJC(A)}}$	max. 0,036 $^{\circ}\text{C}/\text{W}$ max. 0,035 $^{\circ}\text{C}/\text{W}$
für kathodenseitige Kühlung	for cathode-sided cooling	$\Theta = 180^{\circ}\text{ el, sin}$ DC	$R_{\text{thJC(K)}}$	max. 0,048 $^{\circ}\text{C}/\text{W}$ max. 0,047 $^{\circ}\text{C}/\text{W}$
Übergangswärmewiderstand	thermal resistance, case to heatsink	beidseitig/two-sided einseitig/one-sided	R_{thCK}	max. 0,004 $^{\circ}\text{C}/\text{W}$ max. 0,008 $^{\circ}\text{C}/\text{W}$
Höchstzul. Sperrschichttemperatur	max. junction temperature		$t_{vj\text{ max}}$	125 $^{\circ}\text{C}$
Betriebstemperatur	Operating temperature		t_{op}	-40 ... + 125 $^{\circ}\text{C}$
Lagertemperatur	storage temperature		t_{stg}	-40 ... + 150 $^{\circ}\text{C}$

Mechanische Eigenschaften

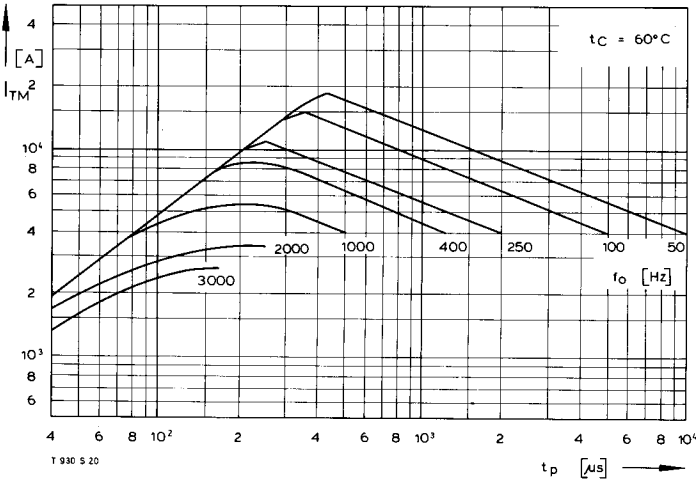
Mechanical properties

Si-Element mit Druckkontakt	Si-pellet with pressure contact		F	16 ... 32 kN
Anpreßkraft	Clamping force		G	typ. 600 g
Gewicht	weight			30 mm
Kriechstrecke	Creepage distance			C
Feuchteklasse	humidity classification	DIN 40040		50 m/s ²
Schwingfestigkeit	Vibration resistance	f = 50 Hz		Seite/page 155
Maßbild	outline	DIN 41814-155B4		

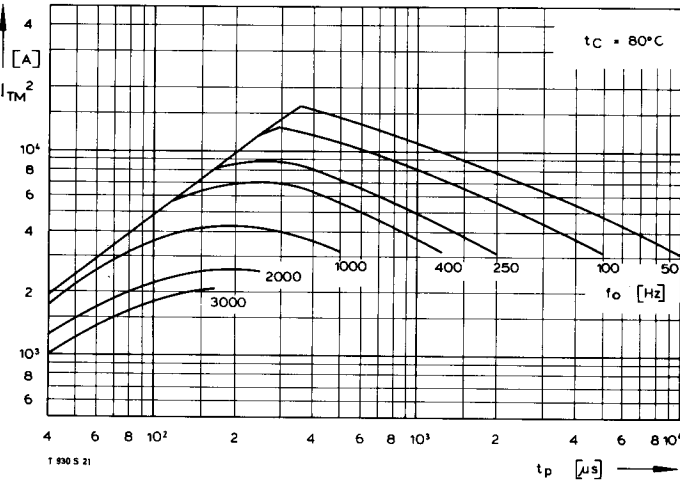
* Für größere Stückzahlen bitte Liefertermin erfragen/Delivery for larger quantities on request

1) Werte nach DIN IEC 747-6 (ohne vorausgehende Kommutierung)/Values to DIN IEC 747-6 (without prior commutation)

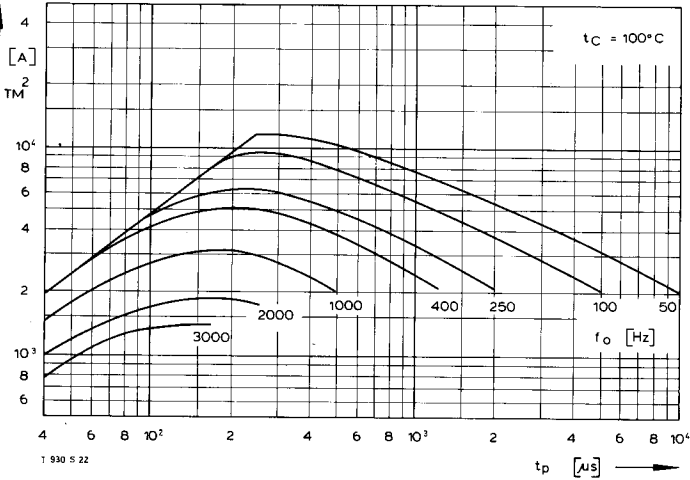
2) Unmittelbar nach der Freiwerdezeit, vgl. Meßbedingungen für t_q /Immediately after circuit commutated turn-off time, see Parameters t_q



Bild/Fig. 1



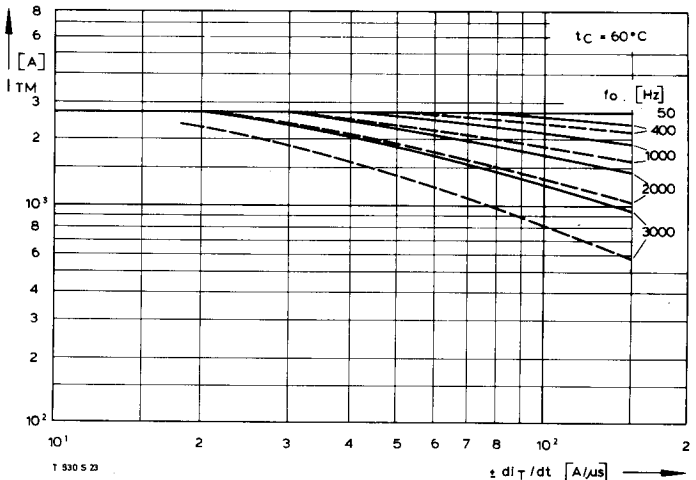
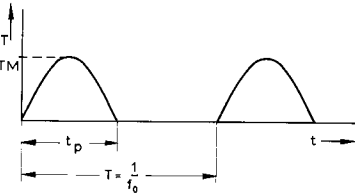
Bild/Fig. 2



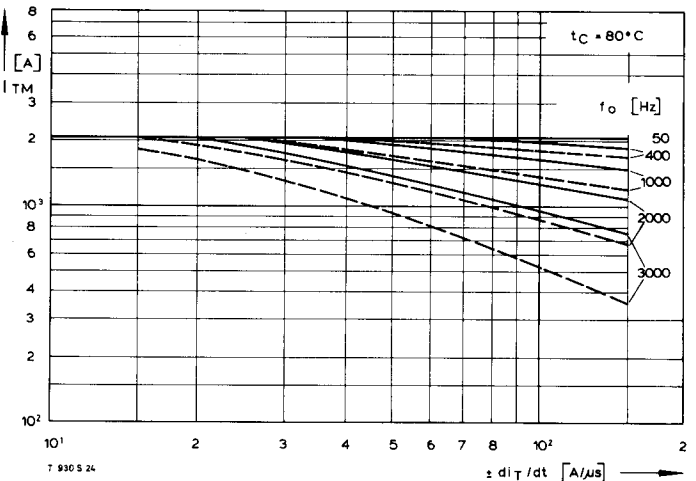
Bild/Fig. 3

Bild/Fig. 1, 2, 3
Steuergenerator/pulse generator:
 $i_G = 1,2 A$, $di_G/dt = 1,2 A/\mu s$

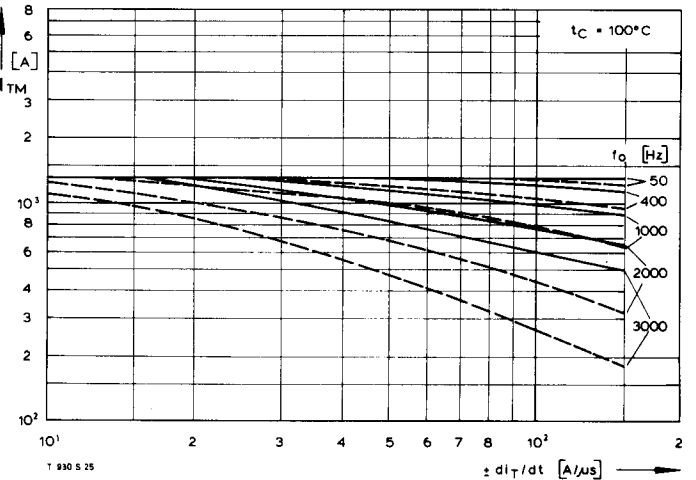
RC-Glied/RC-network:
 $R [\Omega] \geq 0,02 V_{DM} [V]$
 $C \leq 0,33 \mu F$
 $V_{DM} \leq 0,67 V_{DRM}$



Bild/Fig. 4



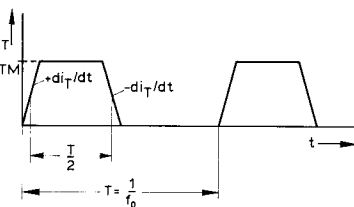
Bild/Fig. 5

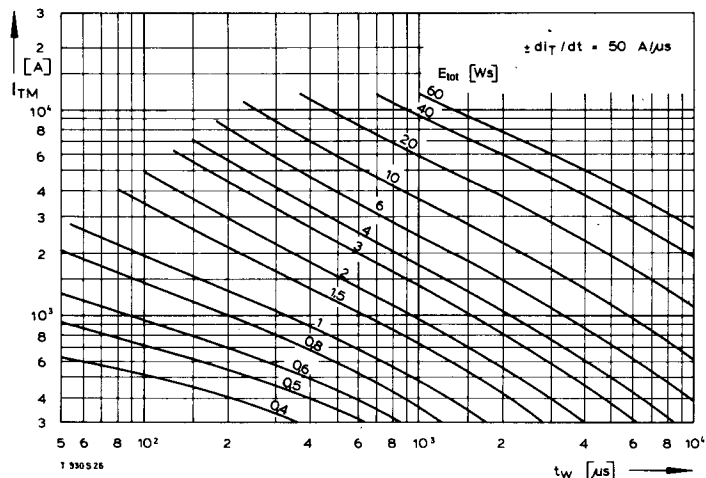


Bild/Fig. 6

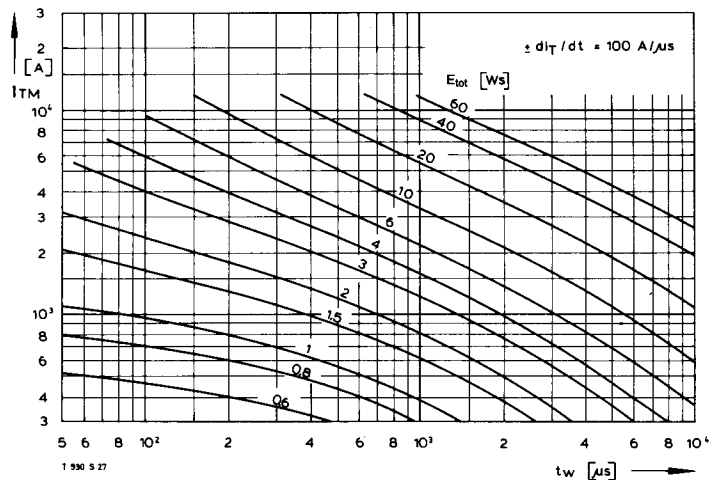
Bild/Fig. 4, 5, 6
Steuergenerator/pulse generator:
 $i_G = 1,2 A$, $di_G/dt = 1,2 A/\mu s$

RC-Glied/RC-network:
 $R [\Omega] \geq 0,02 V_{DM} [V]$
 $C \leq 0,47 \mu F$
 $V_{DM} \leq 0,67 V_{DRM}$
 $dv_R/dt \leq 600 V/\mu s$
 $V_{RM} \leq 0,67 V_{RRM}$

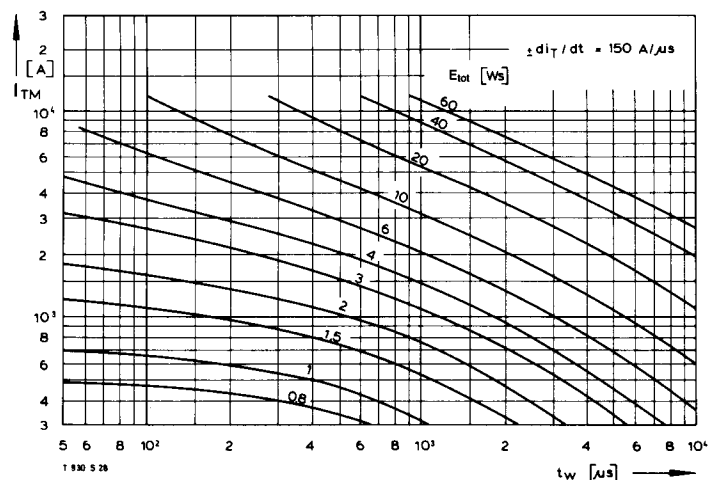




Bild/Fig. 10



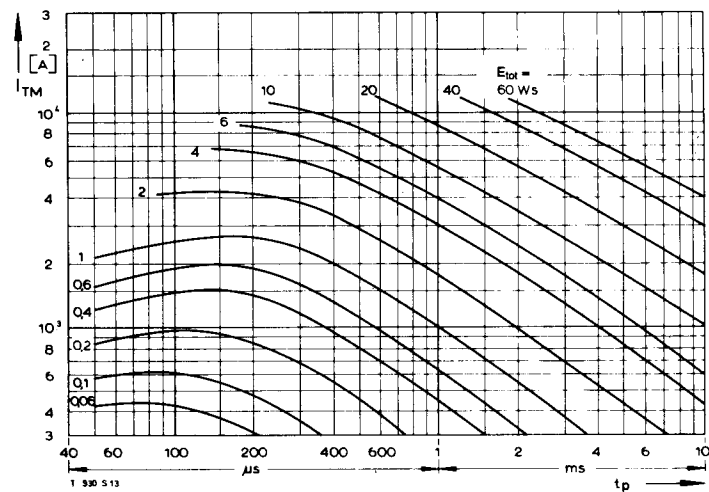
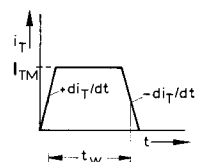
Bild/Fig. 11



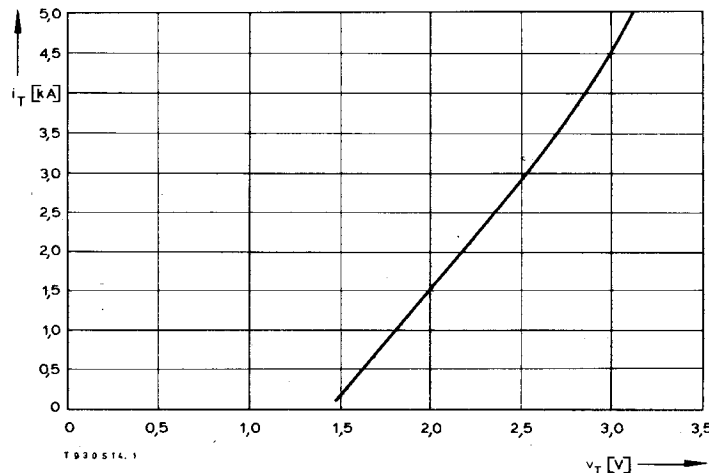
Bild/Fig. 12

Bild/Fig. 10, 11, 12
Steuergenerator/pulse generator:
 $I_G = 1,2 \text{ A}$, $di_G/dt = 1,2 \text{ A/μs}$

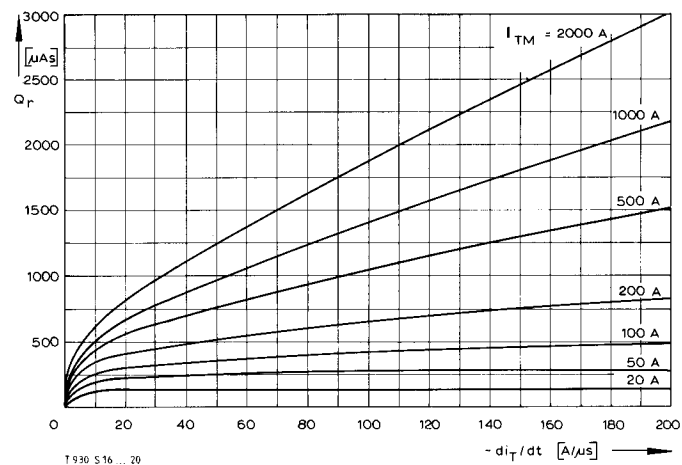
RC-Glied/RC-network:
 $R [\Omega] \geq 0,02 \cdot v_{DM} [\text{V}]$
 $C \leq 0,47 \text{ μF}$
 $v_{DM} \leq 0,67 \cdot v_{DRM}$
 $dv_F/dt \leq 700 \text{ V/μs}$
 $v_{RM} \leq 0,67 \cdot v_{RRM}$



Bild/Fig. 13



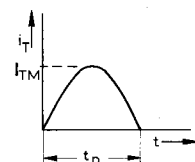
Bild/Fig. 14

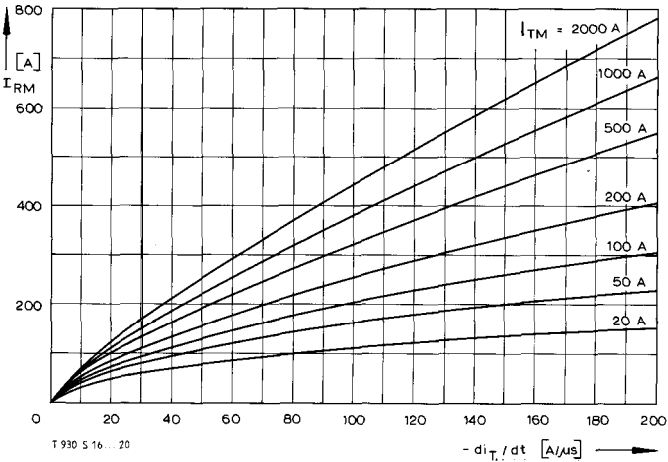


Bild/Fig. 15

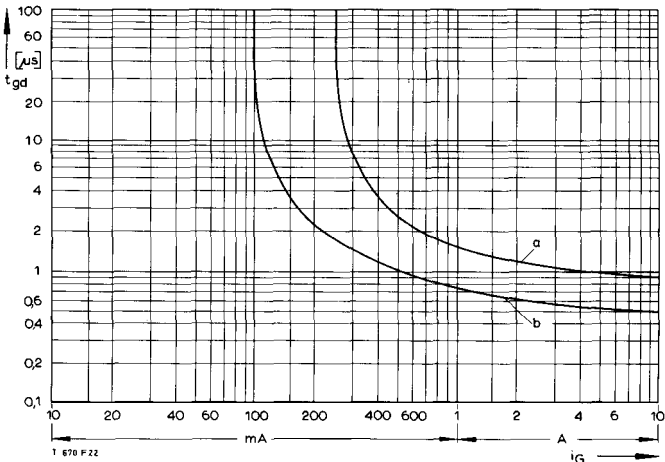
(zu Bild/to Fig. 13)
Steuergenerator/pulse generator:
 $I_G = 1,2 \text{ A}$, $di_G/dt = 1,2 \text{ A/μs}$

RC-Glied/RC-network:
 $R [\Omega] \geq 0,02 \cdot v_{DM} [\text{V}]$
 $C \leq 0,33 \text{ μF}$

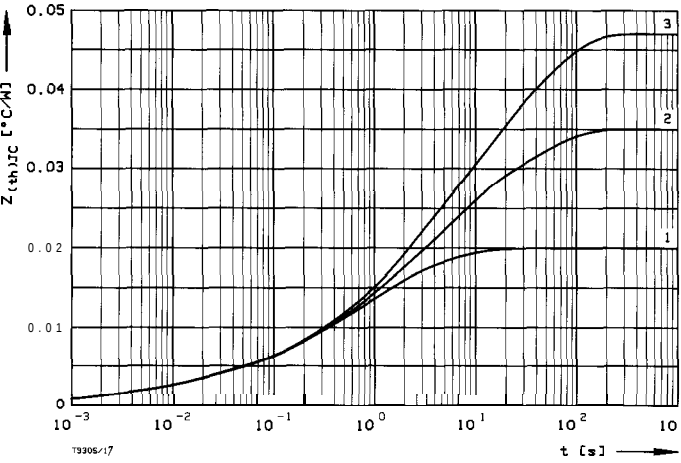




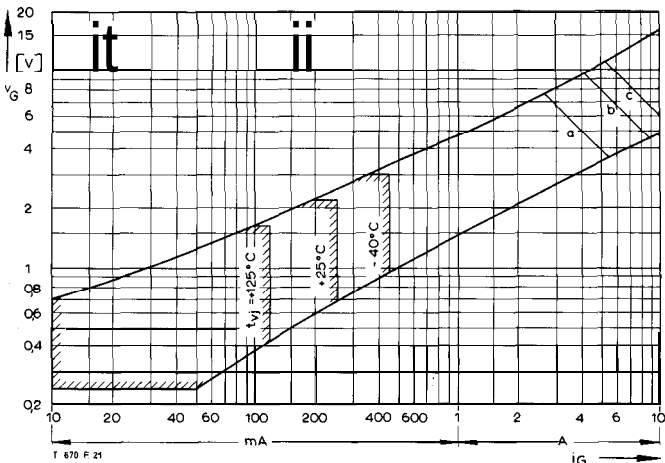
BildFig. 16
Rückstromspitze $I_{RM} = f(-di/dt)$, $t_{vj} = t_{vj(max)}$, $V_R = 0,5 V_{RRM}$, $V_{RM} = 0,8 V_{RRM}$
Peak reverse recovery current $I_{RM} = f(-di/dt)$, $t_{vj} = t_{vj(max)}$, $V_R = 0,5 V_{RRM}$, $V_{RM} = 0,6 V_{RRM}$
Parameter: Durchlaßstrom/On-state current I_{TM}



BildFig. 16
ZündverzugsGate controlled delay time $t_{gd} = f(i_{GM})$, $t_{vj} = 25^\circ\text{C}$, $di_G/dt = i_{GM}/1 \text{ ps}$
a – Maximaler Verlauf/Limiting Characteristic
b – Typischer Verlauf/Typical Characteristic



BildFig. 17
Transienter innerer Wärmewiderstand $Z_{thJC} = f(t)$, DC
Transient thermal impedance $Z_{thJC} = f(t)$, DC
1 Beidseitige Kühlung/two-sided cooling
2 Anodenseitige Kühlung/anode side cooling
3 Kathodenseitige Kühlung/cathode side cooling



Bild/fig. 19
Steuercharakteristik mit Zündbereichen/Gate Characteristic with triggering areas
 $v_G = f(i_G)$, $V_D = 12 \text{ V}$

Parameter:	a	b	c
Steuerimpulsdauer/Trigger pulse duration t_g [ms]	10	1	0,5
Höchstzulässige Spitzensteuerverlustleistung/ Max. rated peak gate power dissipation P_{GM} [W]	20	40	60

Analytische Elemente des transienten Wärmewiderstandes Z_{thJC} für DC
Analytical elements of transient thermal impedance Z_{thJC} for DC

Kühlung cooling	Pos. n	1	2	3	4	5	6	7
beidseitig two-sided	$R_{thn} [^\circ\text{C/W}]$	0,00114	0,00224	0,00487	0,00749	0,00426		
	$\tau_n [\text{s}]$	0,0014	0,015	0,17	1,05	5,1		
anodenseitig anode-sided	$R_{thn} [^\circ\text{C/W}]$	0,00106	0,00239	0,004	0,00725	0,0116	0,0087	
	$\tau_n [\text{s}]$	0,0013	0,015	0,16	0,9	5,8	44	
kathodenseitig cathode-sided	$R_{thn} [^\circ\text{C/W}]$	0,00106	0,00245	0,00499	0,0116	0,0127	0,0142	
	$\tau_n [\text{s}]$	0,0013	0,015	0,19	1,7	10,2	53,5	

Analytische Funktionsanalyhcal funchon:

$$Z_{thJC} = \sum_{n=1}^{nmax} R_{thn} (1 - \text{EXP} (-t/\tau_n))$$